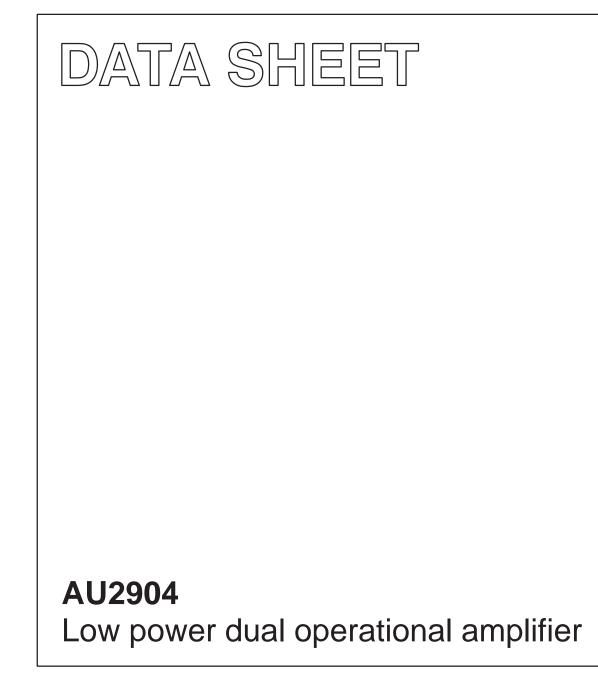
INTEGRATED CIRCUITS



Product data Supersedes data of 1994 Aug 31 File under Integrated Circuits, IC11 Handbook 2001 Aug 03



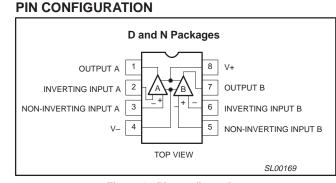
AU2904

DESCRIPTION

The AU2904 consists of two independent, high-gain, internally frequency-compensated operational amplifiers designed specifically to operate from a single power supply over a wide range of voltages. Operation from dual power supplies is also possible, and the low power supply current drain is independent of the magnitude of the power supply voltage.

FEATURES

- Internally frequency-compensated for unity gain
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1 MHz (temperature-compensated)
- Wide power supply range. Single supply: 3 V_{DC} to 30 V_{DC}, or dual supplies: ±1.5 V_{DC} to ±15 V_{DC}
- Very low supply current drain (400 μA): essentially independent of supply voltage (1 mW/op amp at +5 V_{DC})
- Low input bias current: 45 nA_{DC} (temperature-compensated)
- Low input offset voltage: 2 mV_{DC} and offset current: 5 nA_{DC}
- Differential input voltage range equal to the power supply voltage
- Large output voltage: 0 V_{DC} to V+ -1.5 V_{DC} swing





UNIQUE FEATURES

In the linear mode the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

The unity gain crossover frequency and the input bias current are temperature-compensated.

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
8-Pin Plastic Dual In-Line Package (DIP)	–40 $^{\circ}$ C to +125 $^{\circ}$ C	AU2904N	SOT97-1
8-Pin Plastic Small Outline (SO) Package	–40 °C to +125 °C	AU2904D	SOT96-1

EQUIVALENT SCHEMATIC

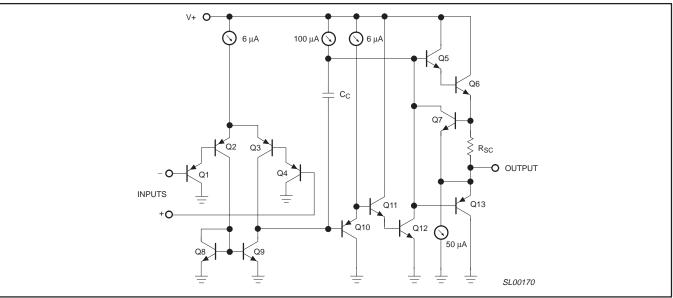


Figure 2. Equivalent schematic.

AU2904

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
Vs	Supply voltage V+	32 or ±16	V _{DC}
	Differential input voltage	32	V _{DC}
V _{IN}	Input voltage	-0.3 to +32	V _{DC}
P _{D(max)}	Maximum power dissipation; T _{amb} = 25 °C (still-air) ¹ N package D package	1160 780	mW mW
	Output short-circuit to GND 2 V+ < 15 V _{DC} and T _{amb} = 25 °C	Continuous	
T _{amb}	Operating ambient temperature range	-40 to +125	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

Derate above 25 °C at the following rates: N package at 9.3 mW/°C D package at 6.2 mW/°C
Short-circuits from the output to V+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40 mA independent of the magnitude of V+. At values of supply voltage in excess of +15 V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.

1. $V_O \approx 1.4 \text{ V}$, $R_S = 0 \Omega$ with V_{CC} from 5 V to 30 V and over full input common-mode range (0 V_{DC} + to V_{CC} -1.5 V). 2. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of

the common-mode voltage range is V+-1.5, but either or both inputs can go to +32 V without damage. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This 4. typically can be detected as this type of coupling increases at higher frequencies.

5. Short-circuits from the output to V+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40 mA independent of the magnitude of V+. At values of supply voltage in excess of +15 V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.

Low power du	al operational	amplifier
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DC ELECTRICAL CHARACTERISTICS

 $T_{amb} = 25 \circ C^2 V_{\pm} = \pm 5 V_{\pm}$ unless otherwise specified.

SYMBOL	DADAMETED	TEST CONDITIONS				
	PARAMETER	TEST CONDITIONS	Min	Тур	Max	
N/	Offeet velterel	R _S = 0 Ω		±2	±3	mV
V _{OS}	Offset voltage ¹	$R_{S} = 0 \Omega$; over temp.			±5	mV
V _{OS}	Drift	$R_{S} = 0 \Omega$; over temp.		7		μV/°C
l _{OS}	Offset current	$I_{IN(+)} - I_{IN(-)}$		±5	±50	nA
		Over temp.			±150	nA
los	Drift	Over temp.		10		pA/°0
	land to summary 2	I _{IN(+)} or I _{IN(-)}		45	250	nA
BIAS	Input current ²	I _{IN(+)} or I _{IN(-)} ; Over temp.		40	500	nA
I _{BIAS}	Drift	Over temp.		50		pA/°C
		V+ = 30 V	0		V+ -1.5	V
V _{CM}	Common-mode voltage range ³	V+ = 30 V; over temp.	0		V+-2.0	V
CMRR	Common-mode rejection ratio	V+ = 30 V	65	70		dB
		$R_L \ge 2 k\Omega$; V+ = 30 V; over temp.	26			V
V _{OH}	Output voltage swing	$R_L \ge 10 \text{ k}\Omega$; V+ = 30 V; over temp.	27	26		V
V _{OL}	Output voltage swing	$R_L \ge 10 \text{ k}\Omega$; Over temp.		5	20	mV
I _{CC}	Supply current	R _L = ∞; V+ = 30 V		0.5	1.0	mA
		$R_L = \infty$ on all amplifiers; V+ = 30 V; Over temp.		0.6	1.2	mA
A _{VOL}	Large-signal voltage gain			100		V/m\
PSRR	Supply voltage rejection ratio	Over temp.	15	100		V/m\
PORK	Supply voltage rejection ratio Amplifier-to-amplifier coupling ⁴	$R_{S} = 0 \Omega$	65	-120		dB dB
		f = 1 kHz to 20 kHz (input referred)	20	40		mА
	Output current Source	$V_{IN+} = +1 V_{DC}; V_{IN-} = 0 V_{DC}; V_{+} = 15 V_{DC}$ Over temp.	10	20		
		$V_{IN-} = +1 V_{DC}; V_{IN+} = 0 V_{DC}; V_{+} = 15 V_{DC}$	10	20		mA mA
lout	Output current Sink	$V_{IN-} = +1 V_{DC}$, $V_{IN+} = 0 V_{DC}$, $V_{+} = 15 V_{DC}$ $V_{IN-} = +1 V_{DC}$; $V_{IN+} = 0 V_{DC}$; $V_{+} = 15 V_{DC}$; Over temp.	5	8		mA
		$V_{IN+} = 0 V; V_{IN-} = +1 V_{DC}; V_{O} = 200 \text{ mV}$	12	50		μA
lsc	Short circuit current ⁵			40	60	mA
	Differential input voltage ³				V+	V
GBW	Unity gain bandwidth	T _{amb} = 25 °C		1		MHz
SR	Slew rate	T _{amb} = 25 °C		0.3		V/µs
V _{NOISE}	Input noise voltage	$T_{amb} = 25 \text{ °C}; f = 1 \text{ kHz}$		40		nV/√⊦

Philips Semiconductors

AU2904

TYPICAL PERFORMANCE CHARACTERISTICS

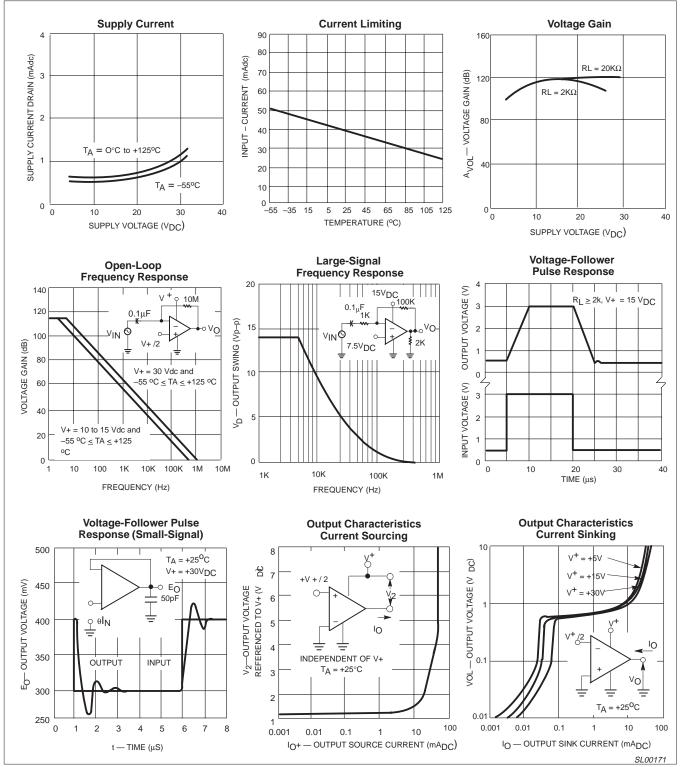


Figure 3. Typical performance characteristics.

Product data

AU2904

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Product data

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

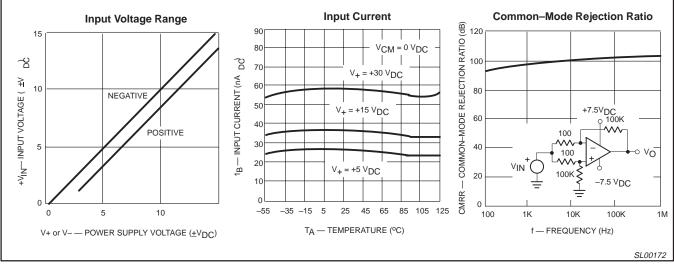


Figure 4. Typical performance characteristics (continued)

TYPICAL APPLICATIONS

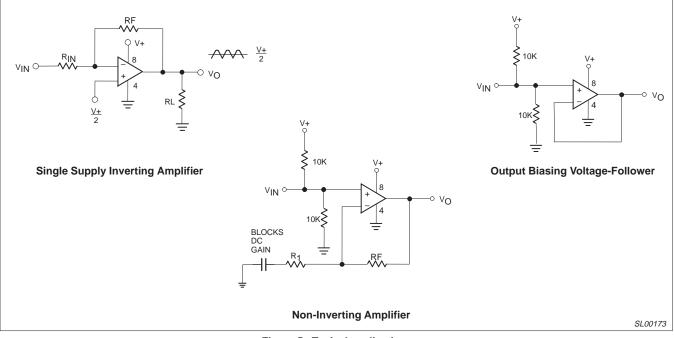


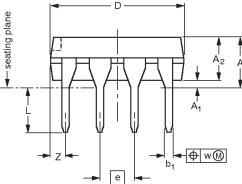
Figure 5. Typical applications.

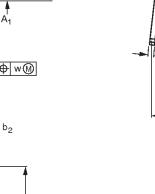
DIP8:

Low power dual operational amplifier

plastic dual in-line package; 8 leads (300 mil)







 M_{E}

(e₁) M_H



4



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

pin 1 index

	JNIT	A max.	A ₁ min.	A ₂ max.	Ь	b ₁	b ₂	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	м _н	w	Z ⁽¹⁾ max.
	mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	1.15
ir	nches	0.17	0.020	0.13	0.068 0.045	0.021 0.015	0.042 0.035	0.014 0.009	0.39 0.36	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.045

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

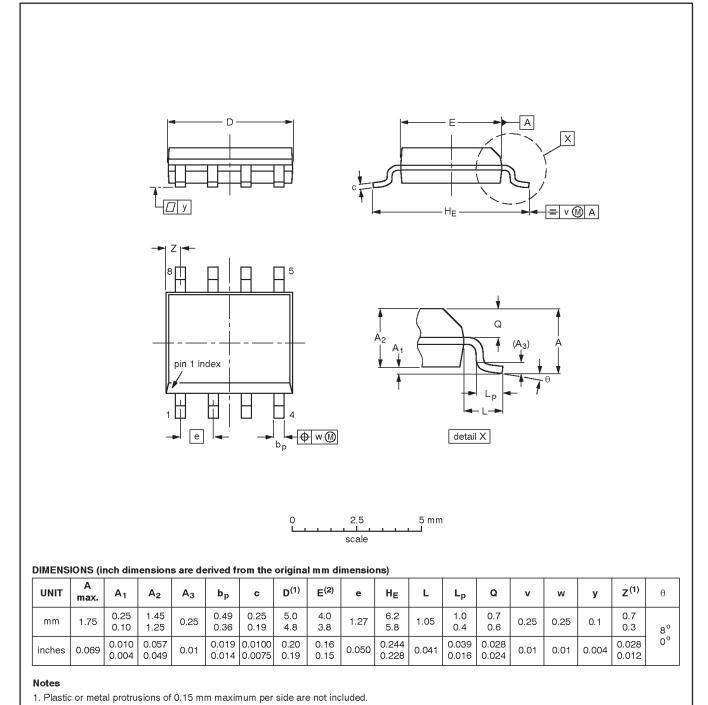
OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE		
SOT97-1	050G01	MO-001	SC-504-8		-95-02-04 99-12-27		

AU2904

SOT97-1

2001 Aug 03





AU2904

SOT96-1

REFERENCES OUTLINE EUROPEAN **ISSUE DATE** PROJECTION VERSION IEC JEDEC EIAJ 97-05-22]⊕ SOT96-1 076E03 MS-012 E---99-12-27

2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

NOTES

9

AU2904

AU2904

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Data sheet status ^[1]	Product status ^[2]	Definitions
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